Applicant: Nigel Langford et al.

Serial No.: Unknown

National Stage Entry: October 12, 2004

Docket: C330.104.101

Title: SEMICONDUCTOR DIODE LASER SPECTROMETER ARRANGEMENT AND METHOD

Amendments to the Claims:

This listing of claims replaces all prior versions, and listings, of claims in the application:

10/511041

DT04 Rec'd PCT/PT0 1 2 OCT 2004

Listing of Claims:

1. (Currently Amended) A method for sensing gases using a diode laser spectrometer, the

method comprising: introducing a sample gas into a non-resonant optical cell having reflecting

elements; applying a step function electrical pulse to a semiconductor diode laser to cause

the laser to output a continuous wavelength chirp for injecting into the optical cell; injecting the

wavelength chirp into the optical cell; using the wavelength variation provided by the wavelength

chirp as a wavelength scan, and detecting light emitted from the cell, wherein the method further

involves-includes using a chirp rate such that there is a time delay between spots on the reflecting

elements sufficient to prevent light interference occurring in the optical cell.

2. (Original) A method as claimed in claim 1, wherein the duration of the pulse applied to the

semiconductor diode laser is equal to or less than one microsecond.

3. (Currently Amended) A method as claimed in claim 1-or claim 2, wherein the duration of the

pulse is less than the duration necessary for the optical output power to become zero after the

drive pulse has been applied.

4. (Currently Amended) A method as claimed in any of the preceding claimsclaim 1 further

involving varying the rate of change of wavelength per unit time.

2

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Docket: C330.104.101

Title: SEMICONDUCTOR DIODE LASER SPECTROMETER ARRANGEMENT AND METHOD

- 5. (Previously Presented) A method as claimed in claim 4 wherein varying the rate of change of the wavelength per unit time involves varying the amplitude of the current/voltage drive pulse.
- 6. (Currently Amended) A method as claimed in any-of-the-preceding claims claim 1 comprising adjusting the wavelength scan length.
- 7. (Previously Presented) A method as claimed in claim 6 wherein adjusting the wavelength scans involves varying the duration of the current/voltage drive pulse.
- 8. (Currently Amended) A method as claimed in any of the preceding claims claim 1 comprising temperature varying the semiconductor diode laser temperature.
- 9. (Currently Amended) A method as claimed in any of the preceding claims 1, wherein the semiconductor diode laser has output radiation having wavelengths in the region of 1 μm to 14 μm.
- 10. (Currently Amended) A method as claimed in any-of the preceding claims claim 1 wherein the semiconductor laser is a quantum cascade laser.
- 11. (Currently Amended) A method as claimed in any of the preceding claims lambda wherein the cell is a Herriot cell.

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12. (Currently Amended) A method as claimed in any of the preceding claimsclaim 1, wherein the amount of radiation absorbed is determined using an amplitude measurement of radiation transmitted through the sample and an amplitude measurement of a reference pulse.

- 13. (Currently Amended) A semiconductor diode laser spectrometer, preferably a quantum radiation cascade laser spectrometer, for measuring absorption by a sample, the spectrometer comprising a semiconductor diode laser; a non-resonant optical cell for containing a sample gas and having reflecting elements at either end thereof; an electric pulse generator adapted to apply a substantially step function electrical pulse to the laser to cause the laser to introduce a continuous wavelength chirp into the sample cell, and a detector for detecting light output from the cell and adapted to use the wavelength variation of the wavelength chirp as a wavelength scan, wherein the chirp rate used is such that there is a time delay between spots on the reflecting elements sufficient to prevent light interference occurring in the optical cell.
- 14. (Previously Presented) A spectrometer as claimed in claim 13, wherein the duration of the electrical pulse is equal to or less than 1 microsecond.
- 15. (Currently Amended) A spectrometer as claimed in claim 13-or clam 14, wherein-further comprising means are provided for varying the rate of change of wavelength per unit time of the chirp.

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16. (Previously Presented) A spectrometer as claimed in claim 15 wherein the means for varying the rate of change of the wavelength are operable to vary the amplitude of the current/voltage drive pulse.

- 17. (Currently Amended) A spectrometer as claimed in any of claims 13 to 16 wherein further comprising means are provided for adjusting the wavelength scan length.
- 18. (Previously Presented) A spectrometer as claimed in claim 17 wherein the means for adjusting the wavelength scan are operable to vary the duration of the electrical pulse.
- 19. (Currently Amended) A spectrometer as claimed in any of claims claim 13 to 18 wherein further comprising means are provided for varying a starting wavelength point of the wavelength scan.
- 20. (Previously Presented) A spectrometer as claimed in claim 19, wherein the means for varying a starting wavelength point are operable to vary the semiconductor diode laser base temperature.
- 21. (Previously Presented) A spectrometer as claimed in claim 20, wherein the means for varying the temperature of the semiconductor diode laser comprise a thermoelectric heater/cooler or means for adjusting the duty cycle or the pulse repetition frequency of the repeated current/voltage drive pulses applied to the electrical contacts of the laser diode or means for adjusting the pulse

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Serial No.: Unknown

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Docket: C330.104.101

Title: SEMICONDUCTOR DIODE LASER SPECTROMETER ARRANGEMENT AND METHOD

amplitude of the current/voltage drive pulses or means for adjusting the base DC level of the current/voltage drive pulses applied to the electrical contacts of the laser diode.

- 22. (Currently Amended) A spectrometer as claimed in any of claimsclaim 13-to 21, wherein a beam splitter or other like element is provided to split radiation output from the laser into two components, the first component for passing through the sample and the a second component that does not pass through the sample.
- 23. (Currently Amended) A spectrometer as claimed in any of-claims claim 13-to 22, wherein the semiconductor diode laser emits radiation having wavelengths in the region of 1 μ m to 14 μ m.
- 24. (Currently Amended) A spectrometer as claimed in any of claimsclaim 13-to 23, wherein the optical cell is a Herriot cell.
- 25. (Currently Amended) A spectrometer as claimed in any of claimsclaim 13-to 24, wherein the chirp has a frequency variation of about 60GHz.
- 26. (Currently Amended) A spectrometer as claimed in any of claims claim 13-to 25, wherein the applied pulse has a duration that is greater than 150ns, in particular greater than 200ns.
- 27. (Currently Amended) A spectrometer as claimed in any of claimsclaim 13 to 25, wherein the applied pulse has a duration that is in the range of 150 to 300ns, preferably 200 to 300ns.